TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WH157FU,TC7WH157FK

2-Channel Multiplexer

The TC7WH157 is an advanced high speed CMOS 2-Channel Multiplexer fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. It consists of 2-input digital multiplexer with common select and strobe inputs.

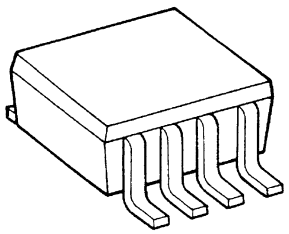
When the $\overline{\text{STROBE}}$ input is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage.

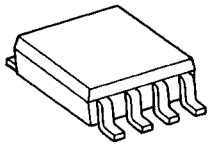
This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

TC7WH157FU



SSOP8-P-0.65

TC7WH157FK



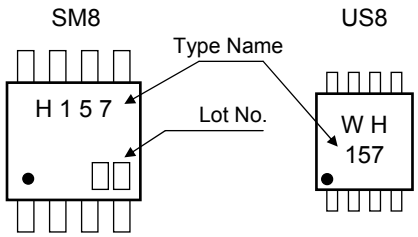
SSOP8-P-0.50A

Weight
SSOP8-P-0.65: 0.02 g (typ.)
SSOP8-P-0.50A: 0.01 g (typ.)

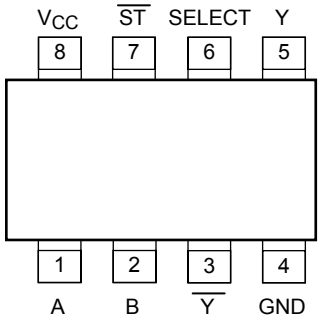
Features

- High speed: t_{pd} = 4.1 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 2 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- 5.5-V Tolerant inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~5.5 V
- Low Noise : V_{OLP} = 0.8 V (max.)

Marking



Pin Assignment (top view)

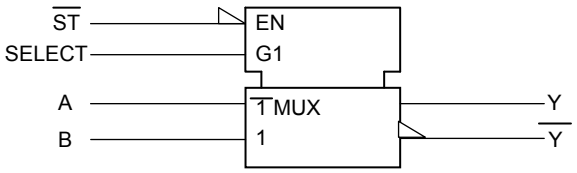


Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	300 (SM8)	mW
		200 (US8)	
Storage temperature	T_{stg}	−65~150	°C
Lead temperature (10 s)	T_L	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Logic Diagram



Truth Table

INPUTS				OUTPUTS	
$\overline{ST}$	SELECT	A	B	Y	$\overline{Y}$
H	X	X	X	L	H
L	L	L	X	L	H
L	L	H	X	H	L
L	H	X	L	L	H
L	H	X	H	H	L

X : Don’t Care

Operating Ranges

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 ± 0.3 V)	ns/V
		0~20 (V_{CC} = 5 ± 0.5 V)	

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40~85°C Min	Ta = −40~85°C Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				3.0~5.5	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				3.0~5.5	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2.0	—	20.0	μA

AC Characteristics (Input: $t_r = t_f = 3$ ns)

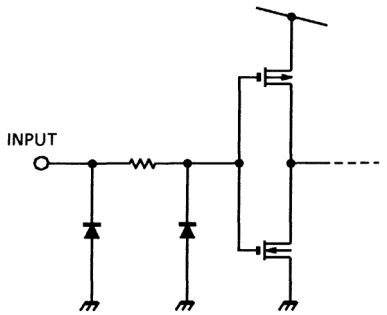
Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	C_L (pF)	Min.	Typ.	Max.	Min.	Max.	
Propagation Delay Time (A, B – Y)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	6.2	9.7	1.0	11.5	ns
				50	—	8.7	13.2	1.0	15.0	
			5.0 ± 0.5	15	—	4.1	6.4	1.0	7.5	
				50	—	5.6	8.4	1.0	9.5	
Propagation Delay Time (SELECT – Y)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	8.4	13.2	1.0	15.5	ns
				50	—	10.9	16.7	1.0	19.0	
			5.0 ± 0.5	15	—	5.3	8.1	1.0	9.5	
				50	—	6.8	10.1	1.0	11.5	
Propagation Delay Time ($\overline{ST}$ – Y)	t_{pLH} t_{pHL}		3.3 ± 0.3	15	—	8.7	13.6	1.0	16.0	ns
				50	—	11.2	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.6	8.6	1.0	10.0	
				50	—	7.1	10.6	1.0	12.0	
Input Capacitance	C_{IN}				—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)			—	20	—	—	—	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation :
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns)

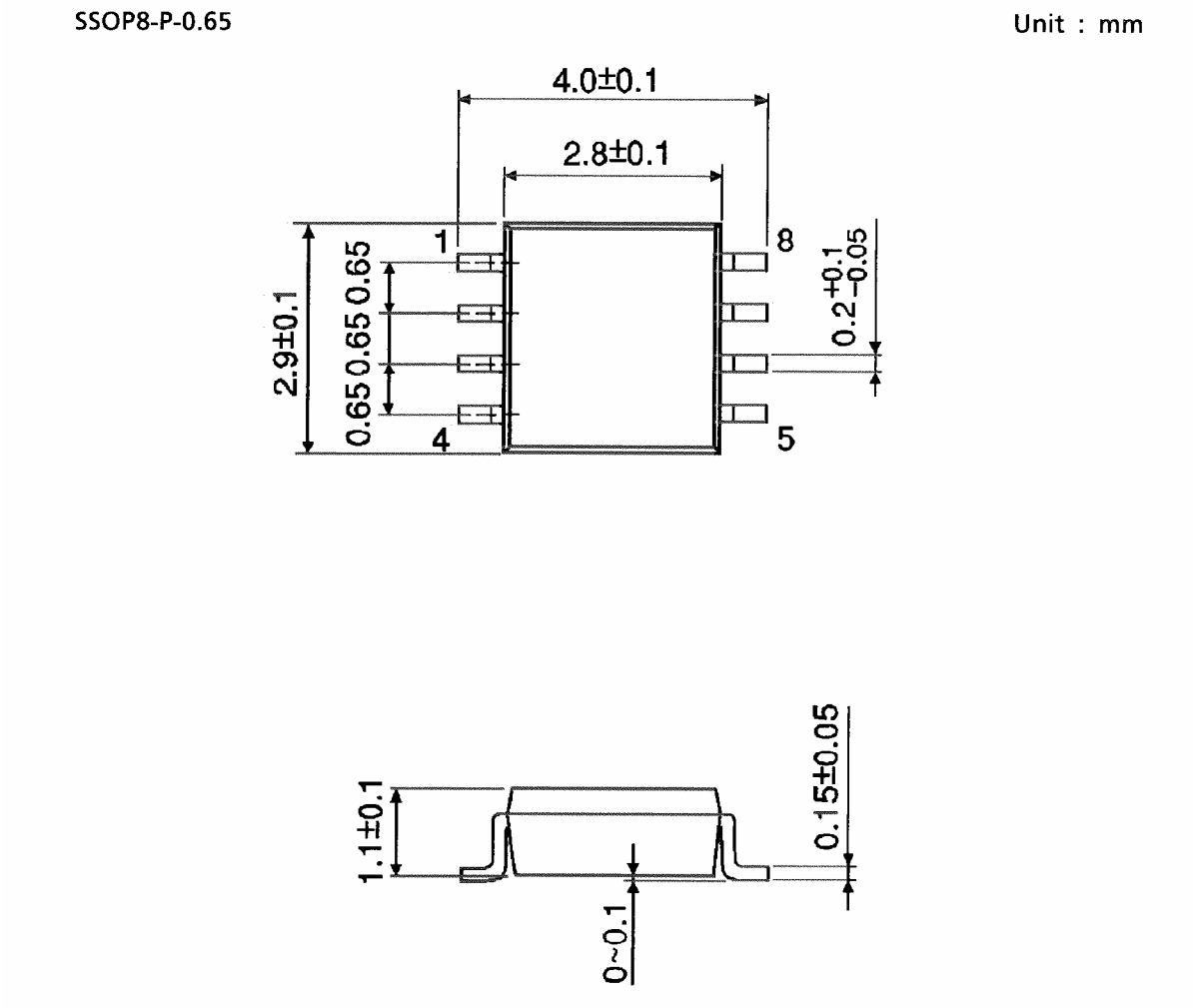
Characteristics	Symbol	Test Condition		Typ.	Limit	Unit
			V_{CC} (V)			
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.3	−0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit



Package Dimensions

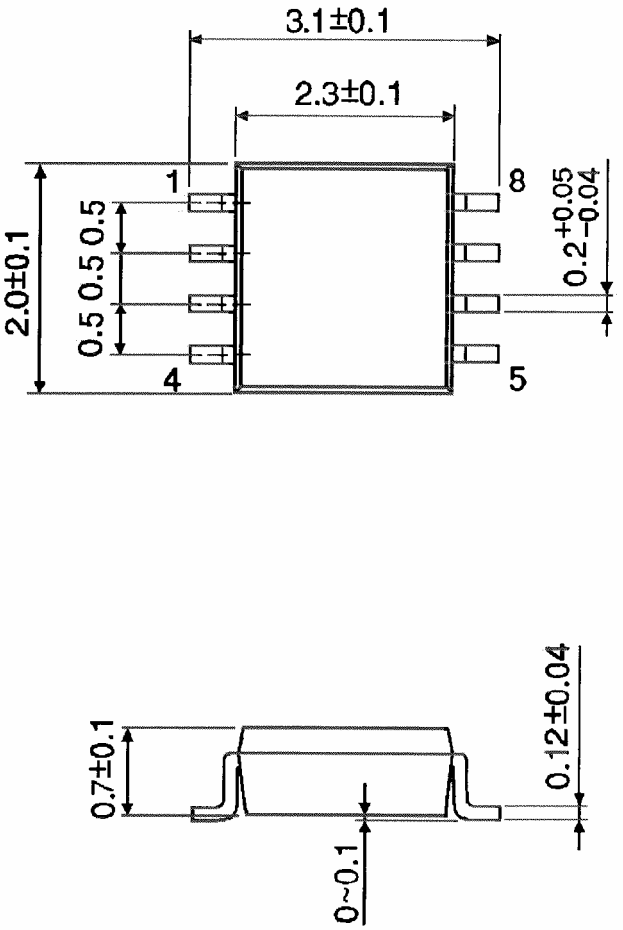
SSOP8-P-0.65 Unit : mm



Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A Unit : mm



Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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